

February 2010

FDP2710_F085

N-Channel PowerTrench[®] MOSFET 250V, 50A, 47m Ω

Features

- Typ $r_{DS(on)}$ = 38m Ω at V_{GS} = 10V, I_D = 50A
- Typ $Q_{g(TOT)}$ = 78nC at V_{GS} = 10V
- Fast switching speed
- Low gate charge
- High performance trench technology for extremely low RDS(on)
- High power and current handling capability
- Qualified to AEC Q101
- RoHS Compliant

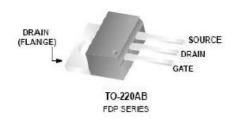
General Description

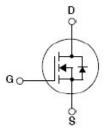
This N-Channel MOSFET is produced using Fairchil Semiconductor's advanced PowerTrench process that has been especially tailored to minimize the on-state resistance and yet maintain superior switching performance.

Applications

- PDP application
- Hybrid Electric Vehicle DC/DC converters







Units

MOSFET Maximum Ratings $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter		Ratings	Units
V_{DSS}	Drain to Source Voltage		250	V
V_{GS}	Gate to Source Voltage		±30	V
	Drain Current Continuous (T _C < 50°C, V _{GS} = 10V)	50		
I_D	Continuous ($T_{amb} = 25^{\circ}C$, $V_{GS} = 10V$, with $R_{\theta JA} = 62^{\circ}C/W$)		4	Α
	Pulsed		See Figure 4	
E _{AS}	Single Pulse Avalanche Energy	(Note 1)	483	mJ
D	Power Dissipation		403	W
P_{D}	Derate above 25°C		3.2	W/°C
T_J , T_{STG}	Operating and Storage Temperature		-55 to +150	°C

Thermal Characteristics

$R_{\theta JC}$	Maximum Thermal Resistance Junction to Case		0.31	°C/W
$R_{\theta JA}$	Maximum Thermal Resistance Junction to Ambient	(Note 2)	62	°C/W

Package Marking and Ordering Information

Parameter

Gate to Source Leakage Current

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDP2710	FDP2710_F085	TO220	Tube	NA	50 units

Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted

Off Characteristics							
B _{VDSS}	Drain to Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS} = 0$	/	250	-	-	V
ΔBV_{DSS} $/\Delta T_{J}$	Breakdown Voltage Temperature Coefficient	I _D = 250μA, Referenced to 25°C		-	0.25	-	V/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 250V, V _{GS} = 0V	T _C = 125°C	-	-	1 500	μА

 $V_{GS} = \pm 30V$

Test Conditions

Min

Тур

On Characteristics

Symbol

 I_{GSS}

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	3	3.9	5	V
	$I_D = 50A, V_{GS} = 10V,$	-	38	47		
r _{DS(on)}	r _{DS(on)} Drain to Source On Resistance	$I_D = 50A, V_{GS} = 10V,$ $T_J = 150^{\circ}C$	-	104	129	mΩ
9 _{FS}	Forward Transconductance	I _D = 25A, V _{DS} = 10V	-	63	-	S

Dynamic Characteristics

C _{iss}	Input Capacitance	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz		-	5690	-	pF
Coss	Output Capacitance			-	425	-	pF
C _{rss}	Reverse Transfer Capacitance			-	115	-	pF
$Q_{g(TOT)}$	Total Gate Charge at 20V	V _{GS} = 0 to 10V	\/ - 405\/	-	78	101	nC
Q _{gs}	Gate to Source Gate Charge		$V_{DD} = 125V$ $I_{D} = 50A$	-	31	-	nC
Q_{gd}	Gate to Drain "Miller" Charge	I _D = 50A		-	20	-	nC

Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Curitob	ing Characteriaties		•		•	

Switching Characteristics

t _{d(on)}	Turn-On Delay Time	., ,,,,,	-	85	-	ns
t _r		$V_{DD} = 125V, I_D = 50A$	-	183	-	ns
t _{d(off)}	Turn-Off Delay Time	V_{GS} = 10V, R_{GEN} = 25 Ω	-	140	-	ns
t _f	Fall Time		-	121	-	ns

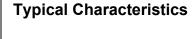
Drain-Source Diode Characteristics

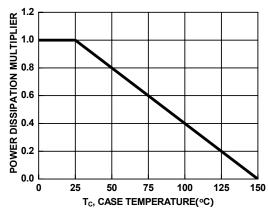
Is	Maximum Continuous Drain-Source D	Maximum Continuous Drain-Source Diode Forward Current		-	50	Α
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current		-	-	150	Α
V_{SD}	Source to Drain Diode Voltage	I _{SD} = 50A	-	0.9	1.2	V
t _{rr}	Reverse Recovery Time	1 - 500 dl /dt = 1000/	-	166	216	ns
Q _{rr}	Reverse Recovery Charge	$I_{SD} = 50A$, $dI_{SD}/dt = 100A/\mu s$	-	1	1.3	uC

- Starting T_J = 25°C, L = 1.68mH, I_{AS} = 24A.
 Pulse width 100s

This product has been designed to meet the extreme test conditions and environment demanded by the automotive industry. For a copy of the requirements, see AEC Q101 at: http://www.aecouncil.com/
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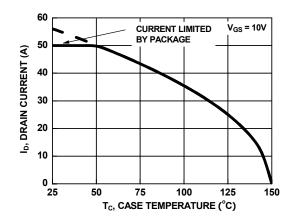


Figure 1. Normalized Power Dissipation vs Case Temperature

Figure 2. Maximum Continuous Drain Current vs Case Temperature

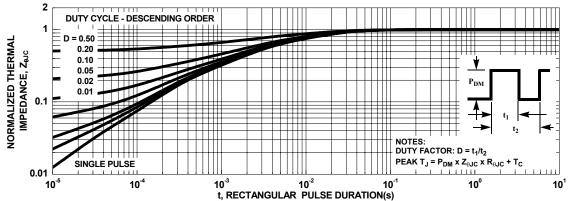


Figure 3. Normalized Maximum Transient Thermal Impedance

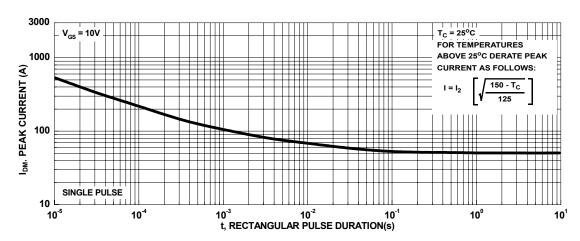


Figure 4. Peak Current Capability

Typical Characteristics

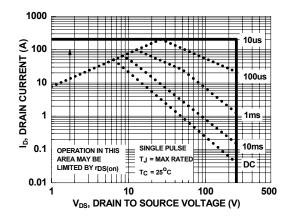
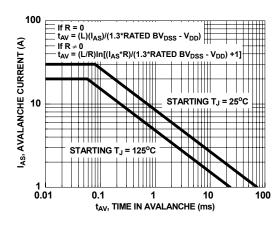


Figure 5. Forward Bias Safe Operating Area



NOTE: Refer to Fairchild Application Notes AN7514 and AN7515

Figure 6. Unclamped Inductive Switching

Capability

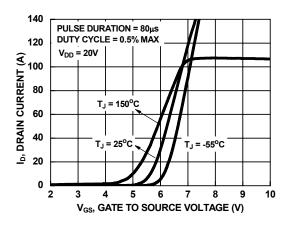


Figure 7. Transfer Characteristics

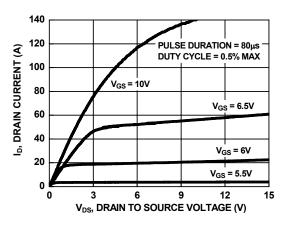


Figure 8. Saturation Characteristics

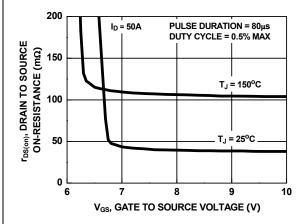


Figure 9. Drain to Source On-Resistance Variation vs Gate to Source Voltage

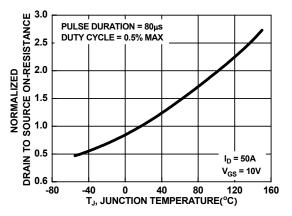


Figure 10. Normalized Drain to Source On Resistance vs Junction Temperature

Typical Characteristics

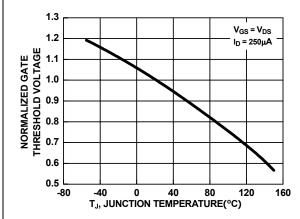


Figure 11. Normalized Gate Threshold Voltage vs Junction Temperature

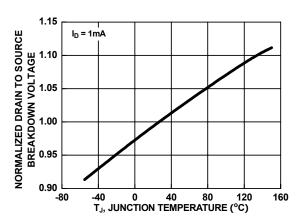


Figure 12. Normalized Drain to Source Breakdown Voltage vs Junction Temperature

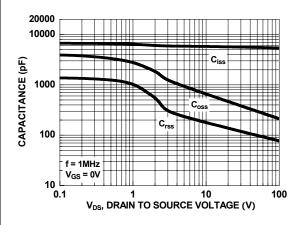


Figure 13. Capacitance vs Drain to Source Voltage

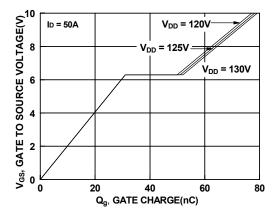


Figure 14. Gate Charge vs Gate to Source Voltage





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